

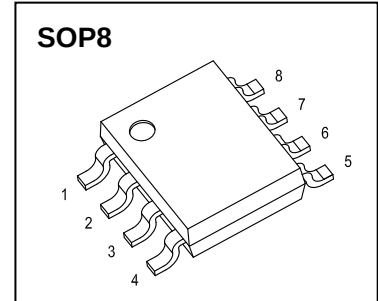


JIANGSU CHANGJING ELECTRONICS TECHNOLOGY CO., LTD.

SOP8 Plastic-Encapsulate MOSFETS

CJQ4435S P-Channel Power MOSFET

$V_{(BR)DSS}$	$R_{DS(on)}$ TYP	I_D
-30V	18m Ω @-10V	-7.3A
	26m Ω @ -4.5V	



DESCRIPTION

The CJQ4435S uses advanced trench technology to provide excellent $R_{DS(on)}$, shoot-through immunity, body diode characteristics and ultra-low gate resistance. This device is ideally suited for use as a low side switch in Notebook CPU core power conversion.

APPLICATIONS

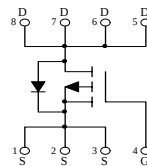
- Battery Switch
- Load Switch

MARKING



Q4435S= Device code
Solid dot=Pin1 indicator
Solid dot = Green molding compound device,
if none, the normal device
YY=Date Code

Equivalent Circuit



MAXIMUM RATINGS ($T_a=25^{\circ}\text{C}$ unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	V_{DS}	-30	V
Gate-Source Voltage	V_{GS}	± 20	V
Continuous Drain Current	I_D	-7.3	A
Pulsed Drain Current	I_{DM}	-27	A
Single Pulsed Avalanche Energy	$E_{AS}^{(1)}$	20	mJ
Power Dissipation	P_D	1.4	W
Thermal Resistance from Junction to Ambient	$R_{\theta JA}$	89	$^{\circ}\text{C/W}$
Junction Temperature	T_J	150	$^{\circ}\text{C}$
Storage Temperature Range	T_{stg}	-55 ~ +150	$^{\circ}\text{C}$

(1). E_{AS} condition: $V_{DD}=-20\text{V}$, $L=0.5\text{mH}$, $R_G=25\Omega$, Starting $T_J = 25^{\circ}\text{C}$

MOSFET ELECTRICAL CHARACTERISTICS

$T_a=25^{\circ}\text{C}$ unless otherwise specified

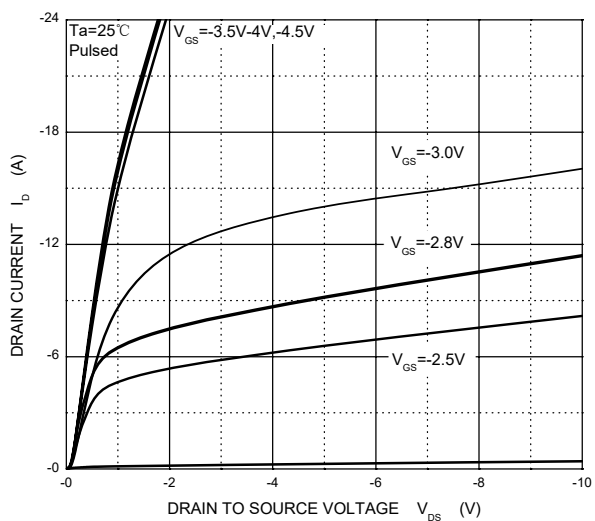
Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
Off characteristics						
Drain-source breakdown voltage	V _{(BR) DSS}	V _{GS} = 0V, I _D =-250μA	-30			V
Zero gate voltage drain current	I _{DSS}	V _{DS} =-30V, V _{GS} =0V			-1	μA
Gate-body leakage current	I _{GSS}	V _{DS} =0V, V _{GS} =±20V			±100	nA
On characteristics (note1)						
Gate-threshold voltage	V _{GS(th)}	V _{DS} =V _{GS} , I _D =-250μA	-1.0	-1.5	-3.0	V
Static drain-source on-sate resistance	R _{DS(on)}	V _{GS} =-10V, I _D =-7.3A		18	24	mΩ
		V _{GS} =-4.5V, I _D =-6.9A		26	35	mΩ
Forward transconductance	g _{FS}	V _{DS} =-10V, I _D =-7.3A		12		S
Dynamic characteristics (note 2)						
Input capacitance	C _{iss}	V _{DS} =-15V,V _{GS} =0V, f =1MHz		1400		pF
Output capacitance	C _{OSS}			165		
Reverse transfer capacitance	C _{rSS}			145		
Switching characteristics (note 2)						
Total gate charge	Q _g	V _{DS} =-15V, V _{GS} =-10V, I _D =-7.3A			42	nC
		V _{DS} =-15V, V _{GS} =-4.5V, I _D =-7.3A			25	
Gate-source charge	Q _{gs}				7	
Gate-drain charge	Q _{gd}				12	
Turn-on delay time	t _{d(on)}	V _{DD} =-15V,I _D =-1A, V _{GS} =-10V,R _G =1Ω, R _L =15Ω			15	ns
Turn-on rise time	t _r				15	
Turn-off delay time	t _{d(off)}				70	
Turn-off fall time	t _f				25	
Drain-Source Diode Characteristics						
Drain-source diode forward voltage(note1)	V _{SD}	V _{GS} =0V, I _S =-2A			-1.2	V
Continuous drain-source diode forward current	I _S				-7.3	A
Pulsed drain-source diode forward current	I _{SM}				-27	A

Notes:

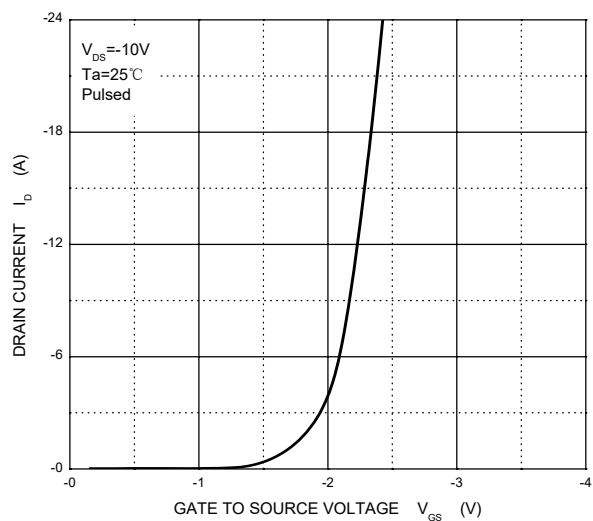
1. Pulse Test : Pulse Width $\leq 300\mu s$, duty cycle $\leq 2\%$.
2. Guaranteed by design, not subject to production testing.

TYPICAL CHARACTERISTICS

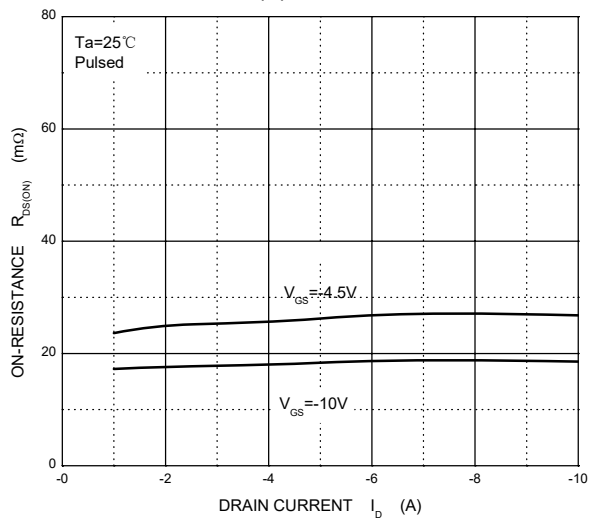
Output Characteristics



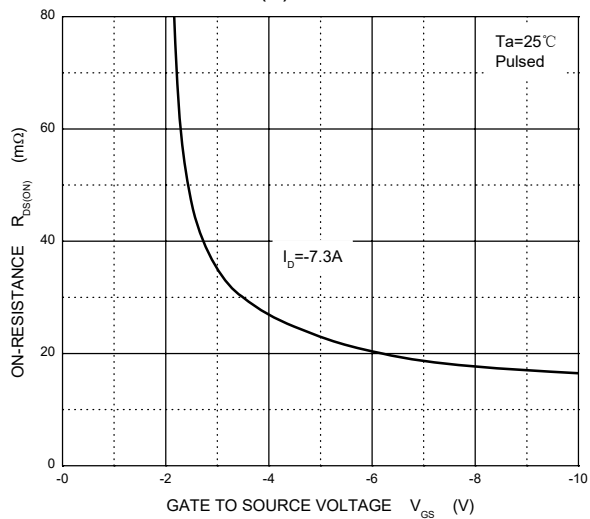
Transfer Characteristics



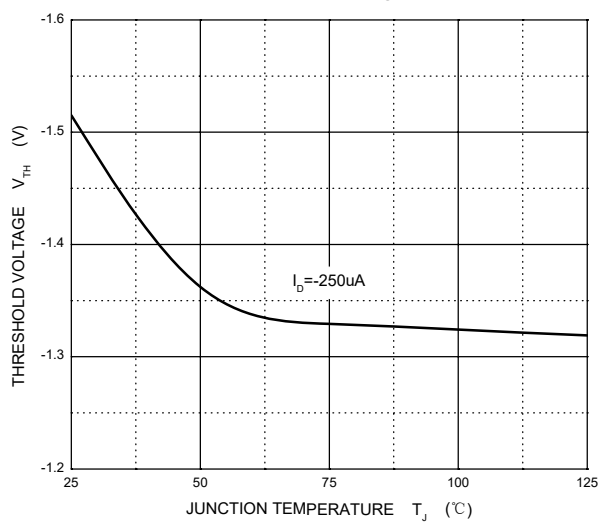
$R_{DS(ON)}$ — I_D



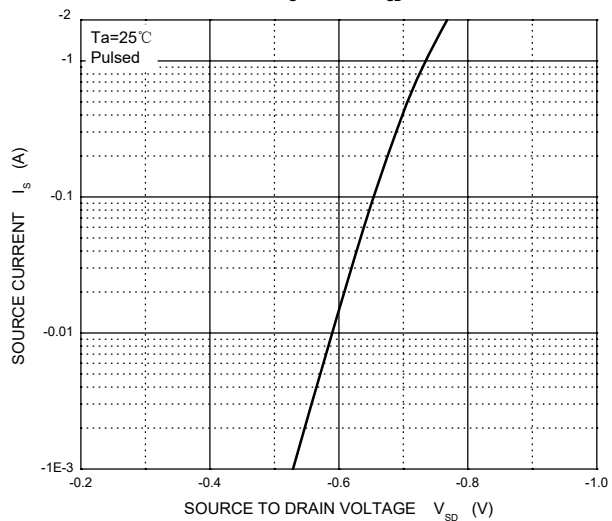
$R_{DS(ON)}$ — V_{GS}



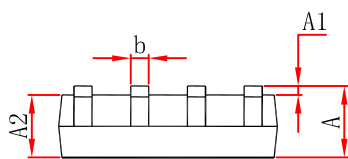
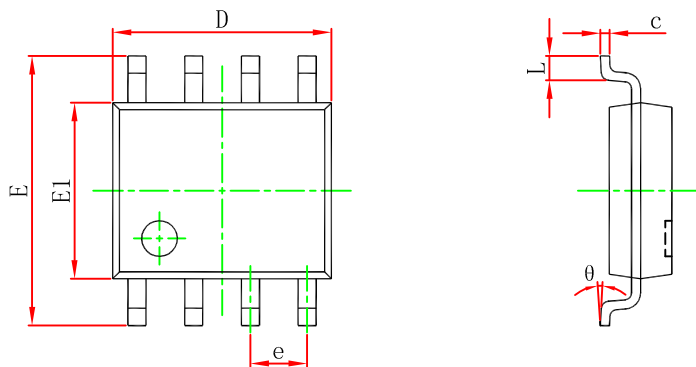
Threshold Voltage



I_S — V_{SD}

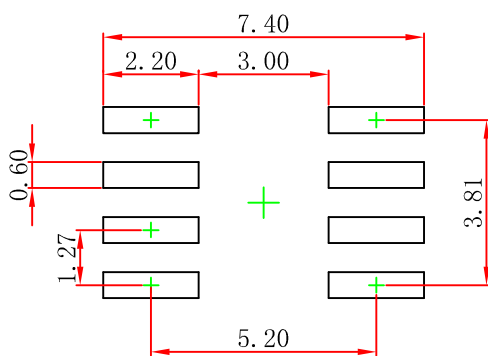


SOP8 Package Outline Dimensions



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	1.450	1.750	0.053	0.069
A1	0.100	0.250	0.004	0.010
A2	1.350	1.550	0.053	0.061
b	0.330	0.510	0.013	0.020
c	0.170	0.250	0.007	0.010
D	4.700	5.100	0.185	0.201
e	1.270 (BSC)		0.050 (BSC)	
E	5.800	6.200	0.228	0.244
E1	3.800	4.000	0.150	0.157
L	0.400	1.270	0.016	0.050
θ	0°	8°	0°	8°

SOP8 Suggested Pad Layout



Note:

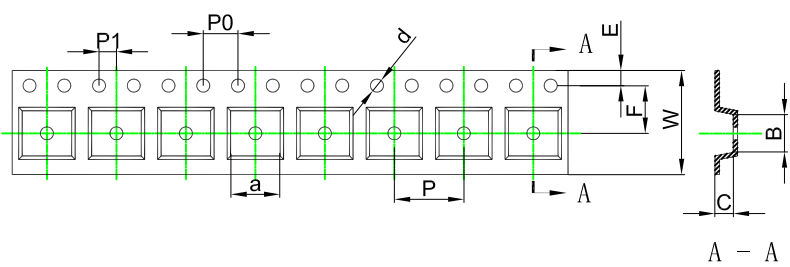
1. Controlling dimension: in millimeters.
2. General tolerance: $\pm 0.05\text{mm}$.
3. The pad layout is for reference purposes only.

NOTICE

JSCJ reserves the right to make modifications, enhancements, improvements, corrections or other changes without further notice to any product herein. JSCJ does not assume any liability arising out of the application or use of any product described herein.

SOP8 Tape and Reel

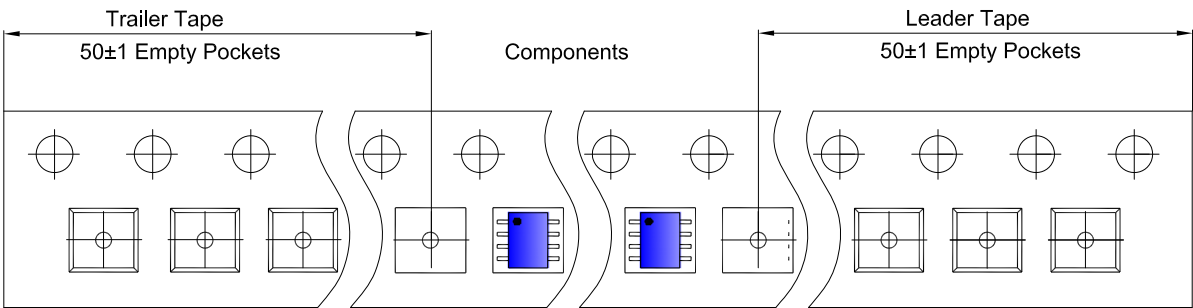
SOP8 Embossed Carrier Tape



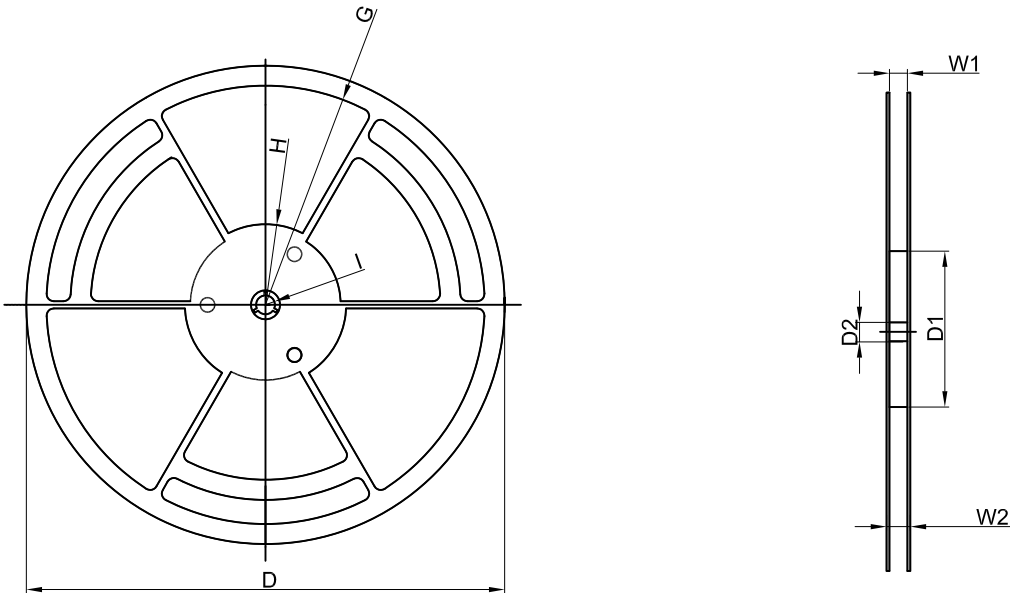
Packaging Description:
SOP8 parts are shipped in tape. The carrier tape is made from a dissipative (carbon filled) polycarbonate resin. The cover tape is a multilayer film (Heat Activated Adhesive in nature) primarily composed of polyester film, adhesive layer, sealant, and anti-static sprayed agent. These reeled parts in standard option are shipped with 4,000 units per 13" or 33cm diameter reel. The reels are clear in color and is made of polystyrene plastic (anti-static coated).
ALL DIM IN mm

Dimensions are in millimeter										
Pkg type	a	B	C	d	E	F	P0	P	P1	W
SOP8	6.40	5.40	2.10	Ø1.50	1.75	5.50	4.00	8.00	2.00	12.00

SOP8 Tape Leader and Trailer



SOP8 Reel



Dimensions are in millimeter								
Reel Option	D	D1	D2	G	H	I	W1	W2
13"Dia	Ø330.00	100.00	13.00	R151.00	R56.00	R6.50	12.40	17.60

REEL	Reel Size	Box	Box Size(mm)	Carton	Carton Size(mm)	G.W.(kg)
4,000 pcs	13 inch	8,000 pcs	360×360×65	40,000 pcs	565×380×390	